

## NCE N-Channel Super Trench Power MOSFET

### Description

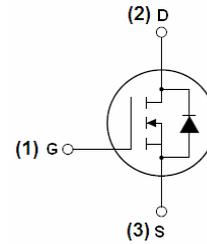
The NCEP85T30T uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of  $R_{DS(ON)}$  and  $Q_g$ . This device is ideal for high-frequency switching and synchronous rectification.

### General Features

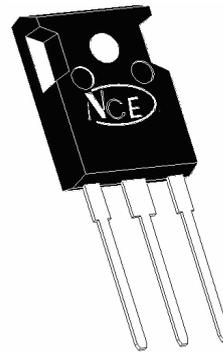
- $V_{DS} = 85V, I_D = 300A$   
 $R_{DS(ON)} < 2.2m\Omega @ V_{GS} = 10V$
- Excellent gate charge x  $R_{DS(on)}$  product
- Very low on-resistance  $R_{DS(on)}$
- 175 °C operating temperature
- Pb-free lead plating
- 100% UIS tested

### Application

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification



Schematic diagram



TO-247 top view

**100% UIS TESTED!**

**100% ΔVds TESTED!**

### Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP85T30T	NCEP85T30T	TO-247	-	-	-

### Absolute Maximum Ratings ( $T_C = 25^\circ C$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	$V_{DS}$	85	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Drain Current-Continuous	$I_D$	300	A
Drain Current-Continuous( $T_C = 100^\circ C$ )	$I_D(100^\circ C)$	215	A
Pulsed Drain Current	$I_{DM}$	1200	A
Maximum Power Dissipation	$P_D$	400	W
Derating factor		2.67	W/°C
Single pulse avalanche energy <sup>(Note 5)</sup>	$E_{AS}$	2300	mJ
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55 To 175	°C

### Thermal Characteristic

Thermal Resistance, Junction-to-Case <sup>(Note 2)</sup>	$R_{\theta JC}$	0.38	°C/W
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## Electrical Characteristics (T<sub>C</sub>=25°C unless otherwise noted)

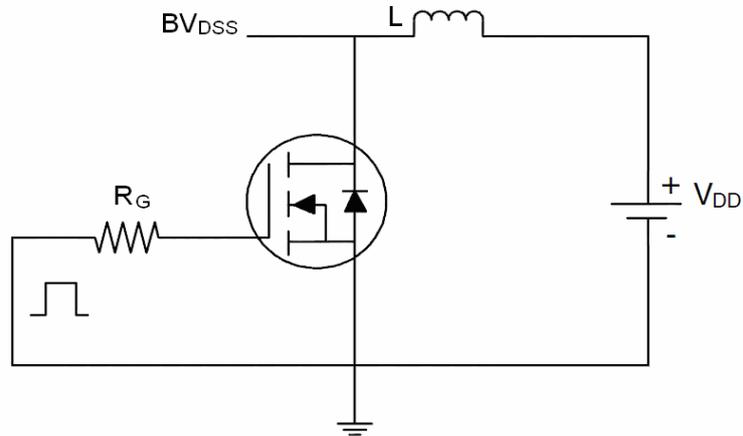
Parameter	Symbol	Condition	Min	Typ	Max	Unit
<b>Off Characteristics</b>						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	85		-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =85V, V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V	-	-	±100	nA
<b>On Characteristics</b> (Note 3)						
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA	2.5	3.5	4.5	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =150A	-	1.75	2.2	mΩ
Forward Transconductance	g <sub>FS</sub>	V <sub>DS</sub> =10V, I <sub>D</sub> =150A	-	100	-	S
<b>Dynamic Characteristics</b> (Note4)						
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =40V, V <sub>GS</sub> =0V, F=1.0MHz	-	14500	-	PF
Output Capacitance	C <sub>oss</sub>		-	2040	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>		-	100	-	PF
<b>Switching Characteristics</b> (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> =40V, I <sub>D</sub> =150A V <sub>GS</sub> =10V, R <sub>G</sub> =1.6Ω	-	30	-	nS
Turn-on Rise Time	t <sub>r</sub>		-	85	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>		-	95	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	38	-	nS
Total Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> =40V, I <sub>D</sub> =150A, V <sub>GS</sub> =10V	-	170		nC
Gate-Source Charge	Q <sub>gs</sub>		-	70		nC
Gate-Drain Charge	Q <sub>gd</sub>		-	40		nC
<b>Drain-Source Diode Characteristics</b>						
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V, I <sub>F</sub> = I <sub>S</sub>	-		1.2	V
Diode Forward Current (Note 2)	I <sub>S</sub>		-	-	300	A
Reverse Recovery Time	t <sub>rr</sub>	T <sub>J</sub> = 25°C, I <sub>F</sub> = I <sub>S</sub> di/dt = 100A/μs (Note3)	-	135		nS
Reverse Recovery Charge	Q <sub>rr</sub>		-	380		nC

### Notes:

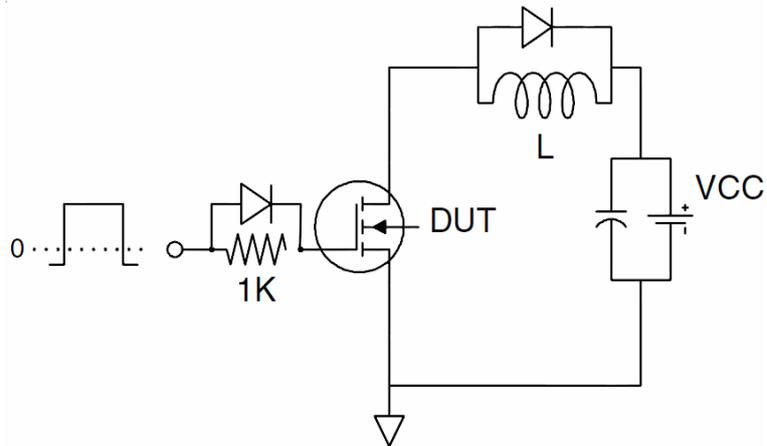
1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board, t ≤ 10 sec.
3. Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2%.
4. Guaranteed by design, not subject to production
5. EAS condition : T<sub>J</sub>=25°C, V<sub>DD</sub>=42.5V, V<sub>G</sub>=10V, L=0.5mH, R<sub>G</sub>=25Ω

## Test Circuit

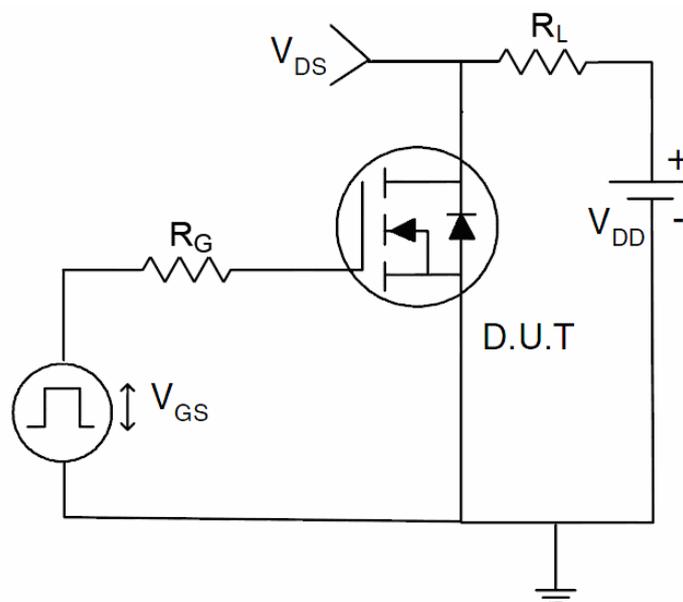
### 1) E<sub>AS</sub> test Circuit



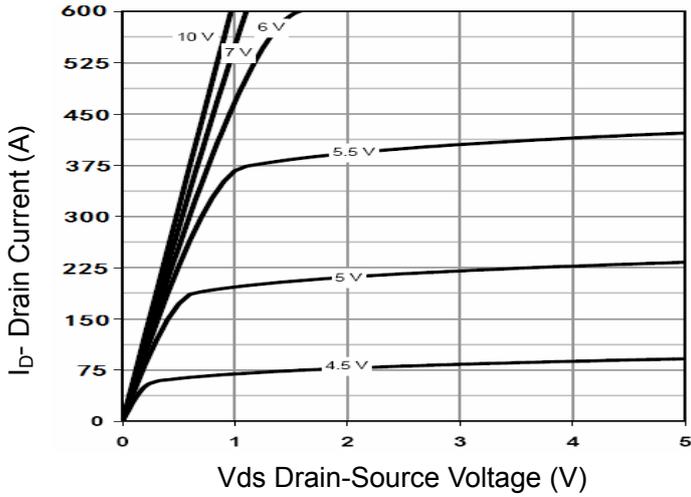
### 2) Gate charge test Circuit



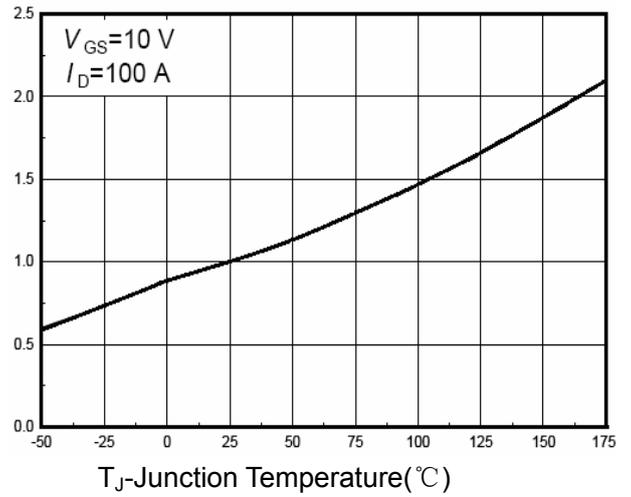
### 3) Switch Time Test Circuit



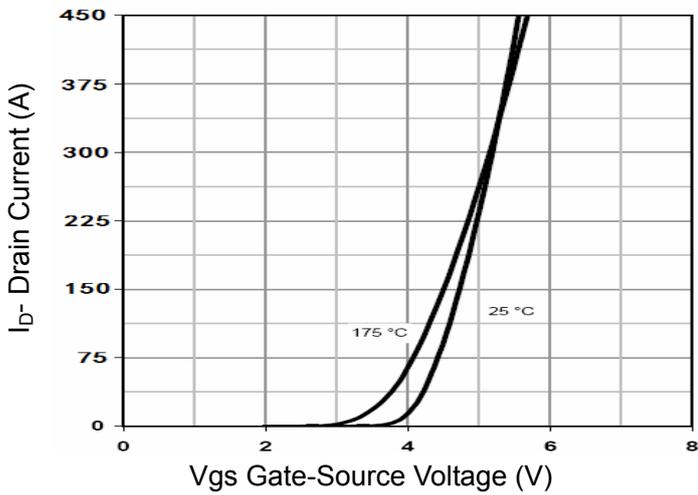
## Typical Electrical and Thermal Characteristics



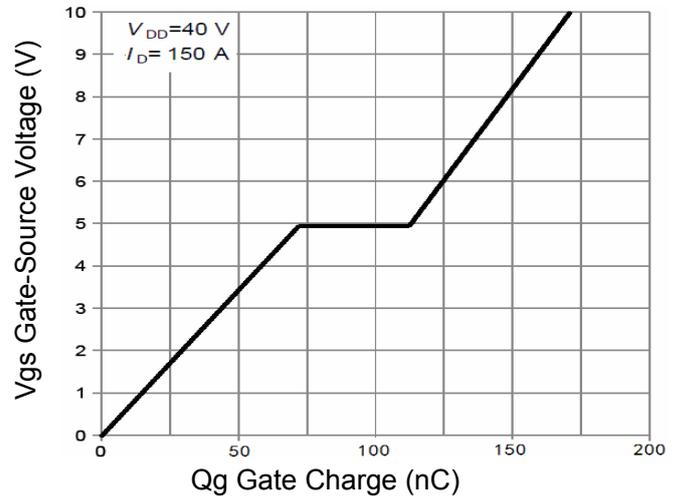
**Figure 1 Output Characteristics**



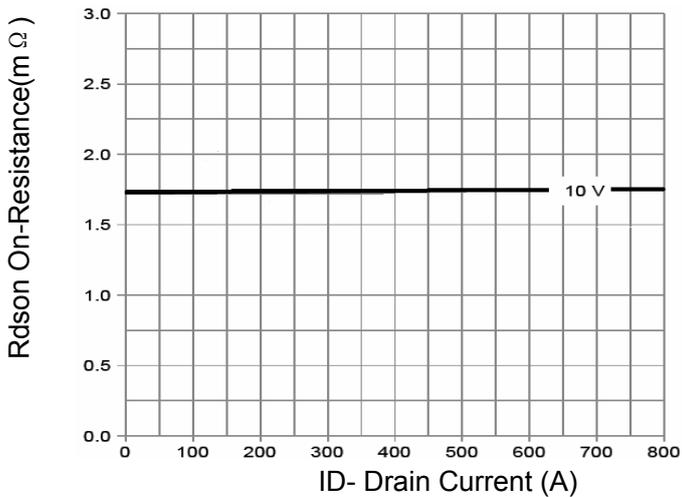
**Figure 4  $R_{DS(on)}$ -Junction Temperature**



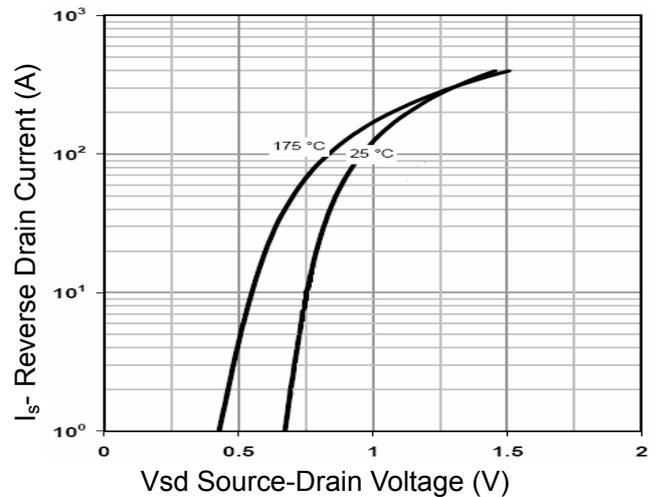
**Figure 2 Transfer Characteristics**



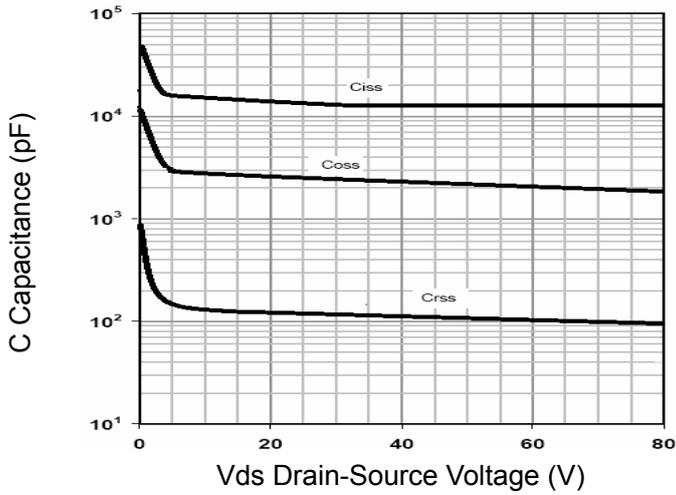
**Figure 5 Gate Charge**



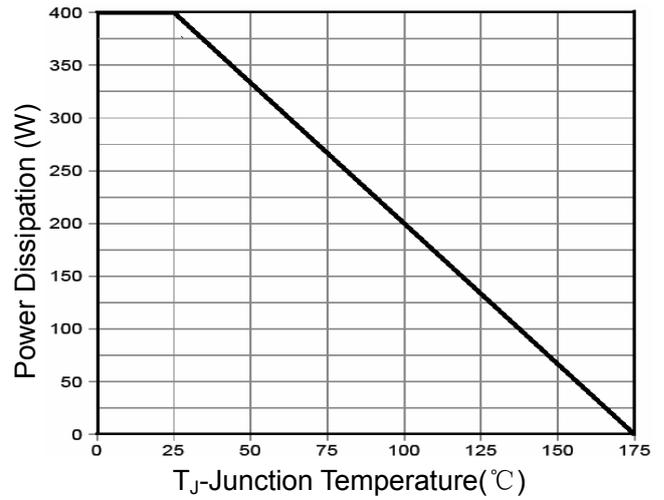
**Figure 3  $R_{DS(on)}$ - Drain Current**



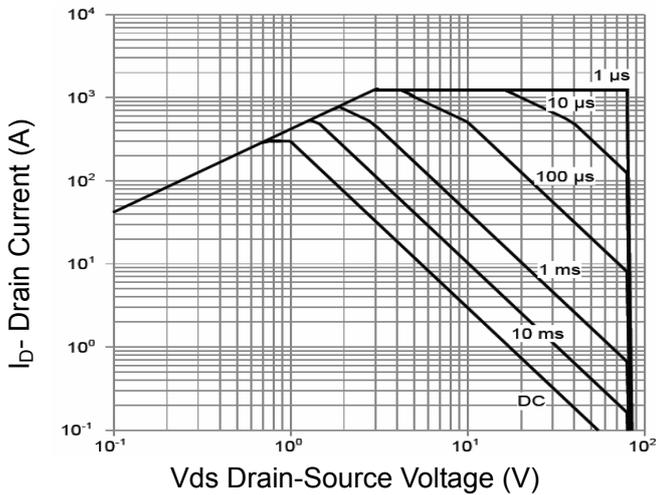
**Figure 6 Source- Drain Diode Forward**



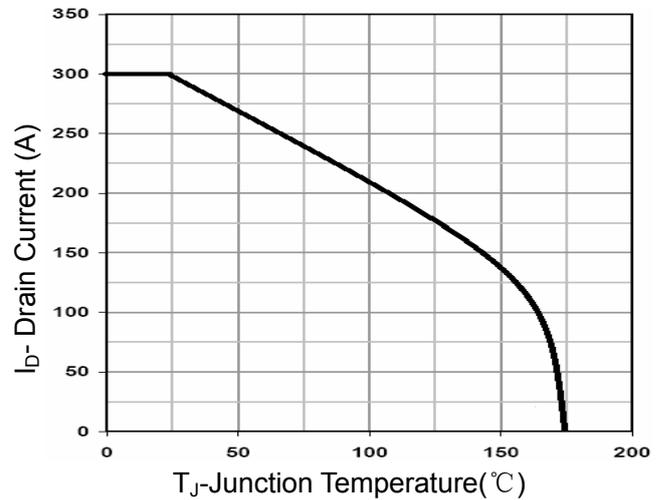
**Figure 7 Capacitance vs Vds**



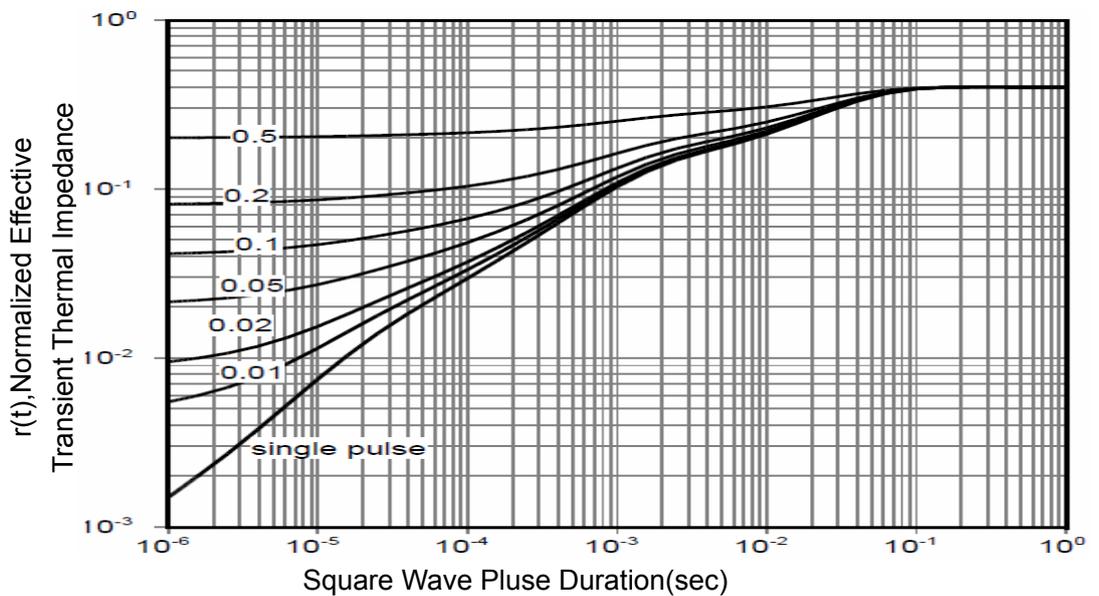
**Figure 9 Power De-rating**



**Figure 8 Safe Operation Area**

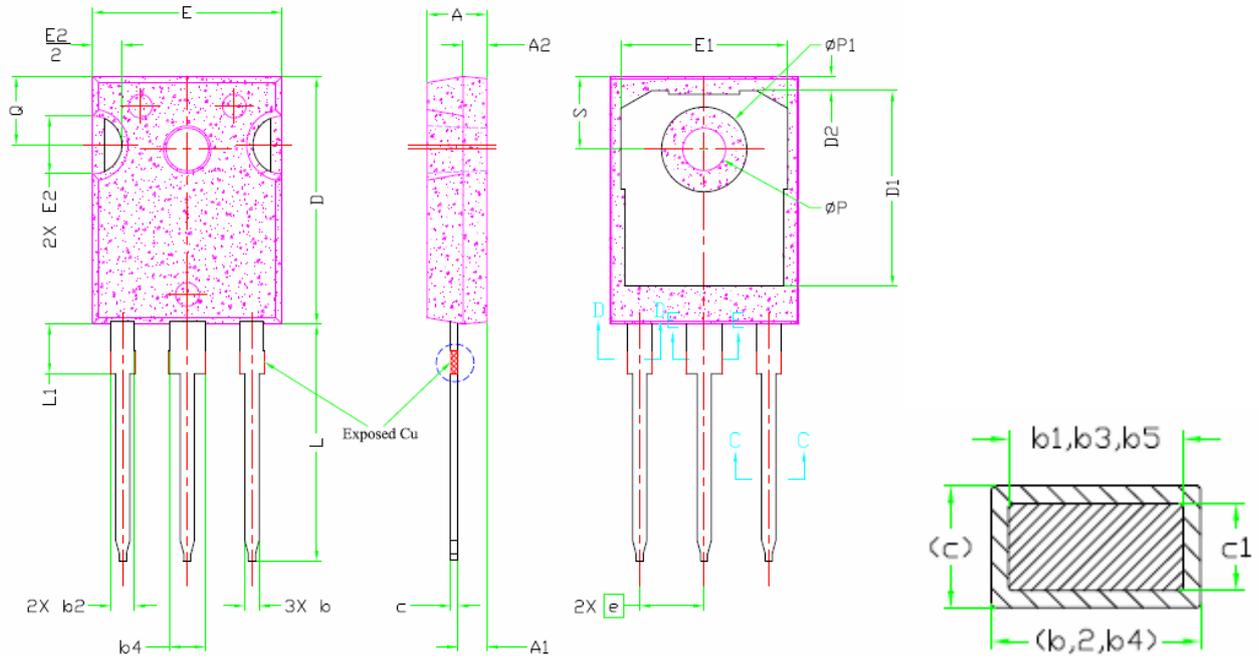


**Figure 10 Current De-rating**



**Figure 11 Normalized Maximum Transient Thermal Impedance**

## TO-247 Package Information



Symbol	Dimensions In Millimeters		
	Min.	Nom.	Max.
A	4.83	5.02	5.21
A1	2.29	2.41	2.55
A2	1.50	2.00	2.49
b	1.12	1.20	1.33
b1	1.12	1.20	1.28
b2	1.91	2.00	2.39
b3	1.91	2.00	2.34
b4	2.87	3.00	3.22
b5	2.87	3.00	3.18
c	0.55	0.60	0.69
c1	0.55	0.60	0.65
D	20.80	20.95	21.1
D1	16.25	16.55	17.65
D2	0.51	1.19	1.35
E	15.75	15.94	16.13
E1	13.46	14.02	14.16
E2	4.32	4.91	5.49
L	19.81	20.07	20.32
L1	4.10	4.19	4.40
Q	5.39	5.79	6.20
ΦP	3.56	3.61	3.65
S	6.04	6.17	6.30

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